

# Voltage references

Voltage references are blocks that produce an output voltage that is independent of **PVT** variations:

**V**: Supply voltage

**T**: Temperature

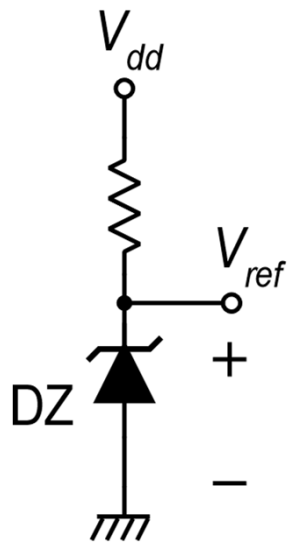
**P**: Process errors

Voltage references are used for:

- Providing an absolute reference voltage for ADCs and DACs
- Providing an absolute reference voltage for stimulating sensors or other external devices that require precise control voltages and/or currents.
- Creating constant bias voltages (and currents) when required

## Possible reference voltage sources

- Zener Diodes



Problems:

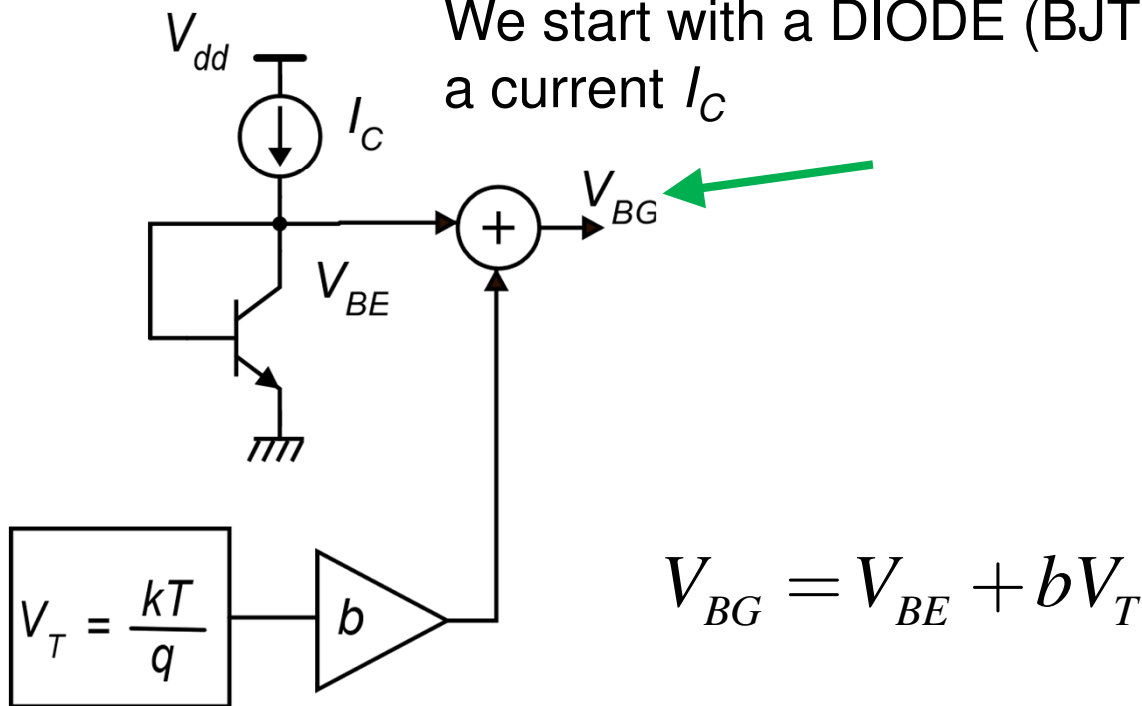
- **Require additional process steps**, but only a small number of components are required for each chip (not convenient)
- **Available voltages are  $> 3\text{ V}$**
- Temperature stability is poor for  $V_Z \neq 5\text{-}6\text{ V}$
- The reference voltage generated by a Zener diode is noisy (very wide band noise)

- Band-gap circuits



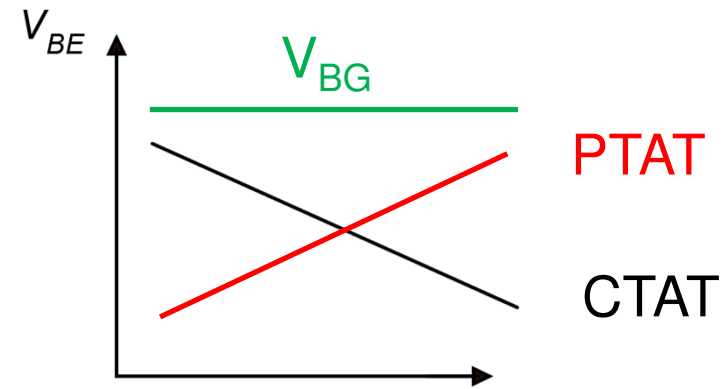
# Band-gap voltage reference: principle of operation

We start with a DIODE (BJT) biased with a current  $I_C$



$$V_{BG} = V_{BE} + bV_T$$

$$\frac{dV_{BE}}{dT} \cong -2 \text{ mV/K} \dots -3 \text{ mV/K}$$



CTAT: Complementary To Absolute Temperature

PTAT: Proportional To Absolute Temperature

## Band-gap voltage reference: determination of parameter $b$

$$V_{BG} = V_{BE} + bV_T \quad \text{We have to determine the value of } b, \text{ for which: } \frac{dV_{BG}}{dT} = 0$$

$$\frac{dV_{BG}}{dT} = \frac{dV_{BE}}{dT} + b \frac{dV_T}{dT} = 0 \quad b = \frac{-\frac{dV_{BE}}{dT}}{\frac{dV_T}{dT}}$$

$$\frac{dV_T}{dT} = \frac{k}{q} \cong 8.56 \times 10^{-5} \text{ V / K}$$

$$b \cong 23$$

Example:

$$\frac{dV_{BE}}{dT} \cong -2 \text{ mV/K}$$

$$V_{BG} \cong \overset{V_{BE}}{\downarrow} 0.65 + \overset{V_T (290 \text{ K})}{\downarrow} 0.025 \times 23 = 1.225 \text{ V}$$

# Band-Gap voltage reference: theory

$$V_{BE} = V_T \ln\left(\frac{I_C}{I_S}\right)$$

$$I_S = \frac{qA_E n_i^2 D_n}{Q_B} = F \cdot n_i^2 D_n$$

*constant*

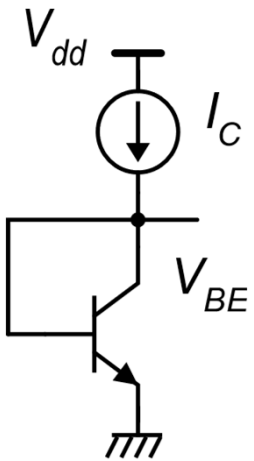
$$\frac{E_{g0}}{kT} = \frac{E_{g0}}{q} \frac{q}{kT} = \frac{V_{G0}}{V_T}$$

$$I_S = BT^\gamma e^{-\frac{V_{G0}}{V_T}}$$

*constant*      *constant*

$\gamma = 4 - \alpha_\mu$   
 $\alpha_\mu \cong 1.5$

$$\left\{ \begin{array}{l} n_i^2 \propto T^3 e^{-\frac{E_{g0}}{kT}} \\ D_n = \mu_n \frac{kT}{q} \\ \mu_n \propto T^{-\alpha_\mu} \end{array} \right.$$



$I_C = GT^\alpha$       It is not necessary that  $I_C$  is constant

$$V_{BE} = V_T \ln\left(\frac{GT^\alpha}{BT^\gamma \exp\left(\frac{-V_{G0}}{V_T}\right)}\right) = V_{G0} + V_T \left[ \ln(G \cdot E) - (\gamma - \alpha) \ln(T) \right]$$

$E = \frac{1}{B}$

Gray, Hurst, Lewis, Meyer, "Analysis and design of analog integrated circuits" 4th edition, 2001 J.Wiley & Sons

## Band-Gap voltage reference: theory

$$V_{BE} = V_{GO} + V_T \left[ \ln(G \cdot E) - (\gamma - \alpha) \ln(T) \right] \quad V_{BG} = V_{BE} + bV_T$$

$$V_{BG} = V_{GO} + V_T \left[ \ln(G \cdot E) + b - (\gamma - \alpha) \ln(T) \right]$$



The name "**band-gap**" of this reference voltage comes from  $V_{GO}$ , which is the dominant part

Let us calculate the derivative of  $V_{BG}$  with respect to temperature

$$\frac{dV_{BG}}{dT} = \frac{k}{q} \left[ \ln(G \cdot E) + b - (\gamma - \alpha) \ln(T) \right] - (\gamma - \alpha) V_T \frac{1}{T}$$

$$\frac{dV_{BG}}{dT} = \frac{k}{q} \left[ \ln(G \cdot E) + b - (\gamma - \alpha) - (\gamma - \alpha) \ln(T) \right]$$

$$V_{GO} = \frac{E_{g0}}{q}$$

$V_{GO}$  is numerically equivalent to  $E_{g0}$  measured in eV

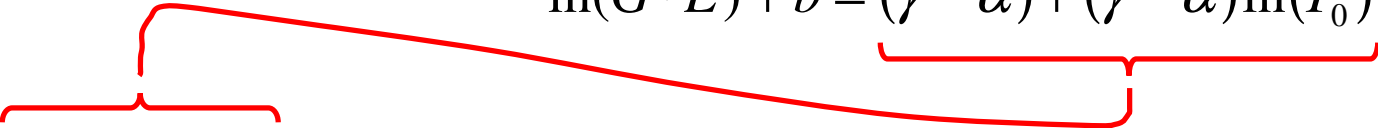
$$E_{g0} \cong 1.2 \text{ eV} \Rightarrow V_{GO} \cong 1.2 \text{ V}$$

The derivative of  $V_{BG}$  depends on temperature

## Band-Gap voltage reference: theory

We impose that the derivative of  $V_{BG}$  is zero at a given temperature  $T_0$

$$\frac{k}{q} \left[ \ln(G \cdot E) + b - (\gamma - \alpha) - (\gamma - \alpha) \ln(T_0) \right] = 0$$

$$\ln(G \cdot E) + b = (\gamma - \alpha) + (\gamma - \alpha) \ln(T_0)$$


$$V_{BG} = V_{G0} + V_T \left[ \ln(G \cdot E) + b - (\gamma - \alpha) \ln(T) \right]$$

$$V_{BG} = V_{G0} + V_T \left[ (\gamma - \alpha) + (\gamma - \alpha) \ln(T_0) - (\gamma - \alpha) \ln(T) \right]$$

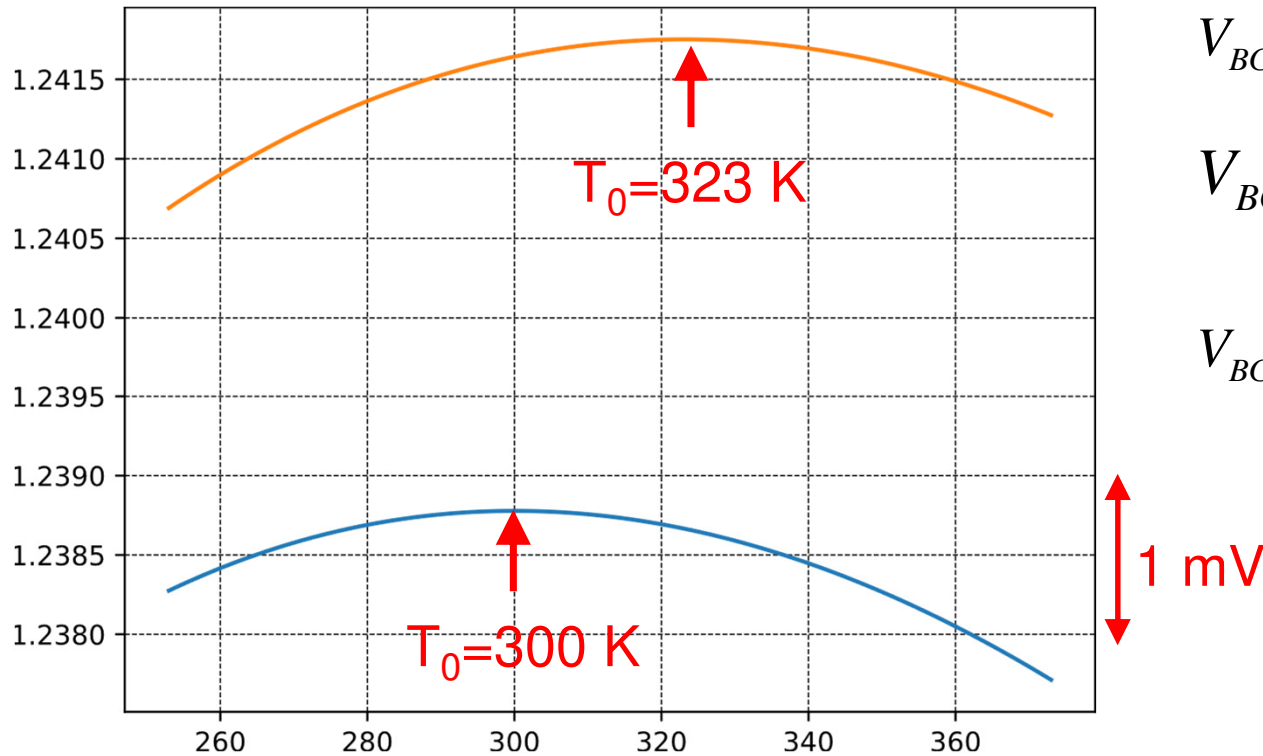
Typically:  $\alpha=1$

$$V_{BG} = V_{G0} + V_T (\gamma - \alpha) \left( 1 + \ln\left(\frac{T_0}{T}\right) \right)$$

$$V_{BG}(T_0) = V_{G0} + \frac{kT_0}{q} (\gamma - \alpha) \cong 1.24 \text{ V}$$

$$\gamma \cong 2.5$$

## Band-gap voltage reference: calculation result



$$V_{BG} = V_{BE} + bV_T$$

$$V_{BG} = V_{G0} + V_T (\gamma - \alpha) \left( 1 + \ln \left( \frac{T_0}{T} \right) \right)$$

$$V_{BG}(T_0) = V_{G0} + \frac{kT_0}{q} (\gamma - \alpha)$$



# Band-Gap voltage: a CMOS compatible Circuit

Q2	Q2	Q2
Q2	Q1	Q2
Q2	Q2	Q2

## Part 1: PTAT current generator

$$M3 = M4 \Rightarrow I_1 = I_2 = I$$

$$M1 = M2$$

neglecting the effects of  $V_{DS}$  on  $I_D$ :

$$V_{GS1} = V_{GS2}$$

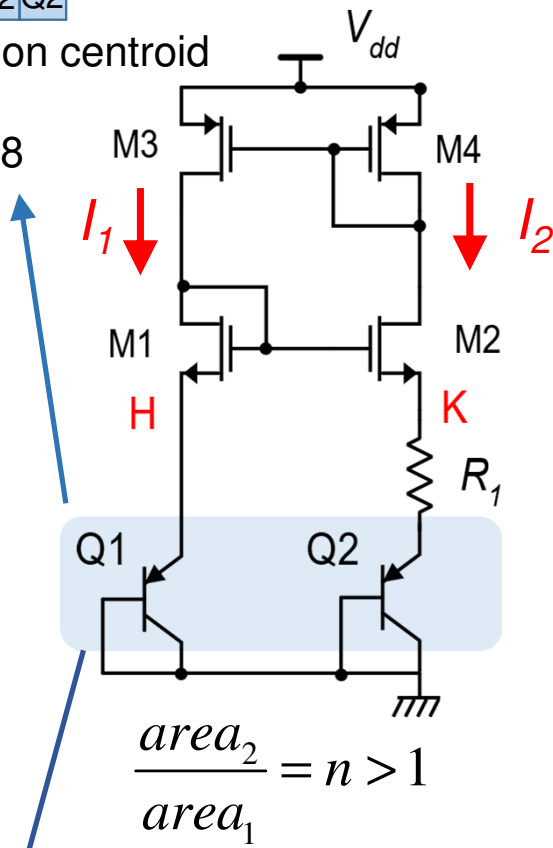
$$V_H - V_K = (V_{G1} - V_{GS1}) - (V_{G2} - V_{GS2}) = V_{GS2} - V_{GS1}$$

$$V_H = |V_{BE1}| \quad V_K = |V_{BE2}| + R_1 I \quad V_H = V_K$$

$$R_1 I = |V_{BE1}| - |V_{BE2}| = V_T \ln \left( \frac{I_{C1} I_{S2}}{I_{S1} I_{C2}} \right) = V_T \ln(n)$$

$$I = \frac{1}{R_1} \frac{kT}{q} \ln(n) \quad I \text{ is proportional to } T \text{ (PTAT) and independent of } V_{dd}$$

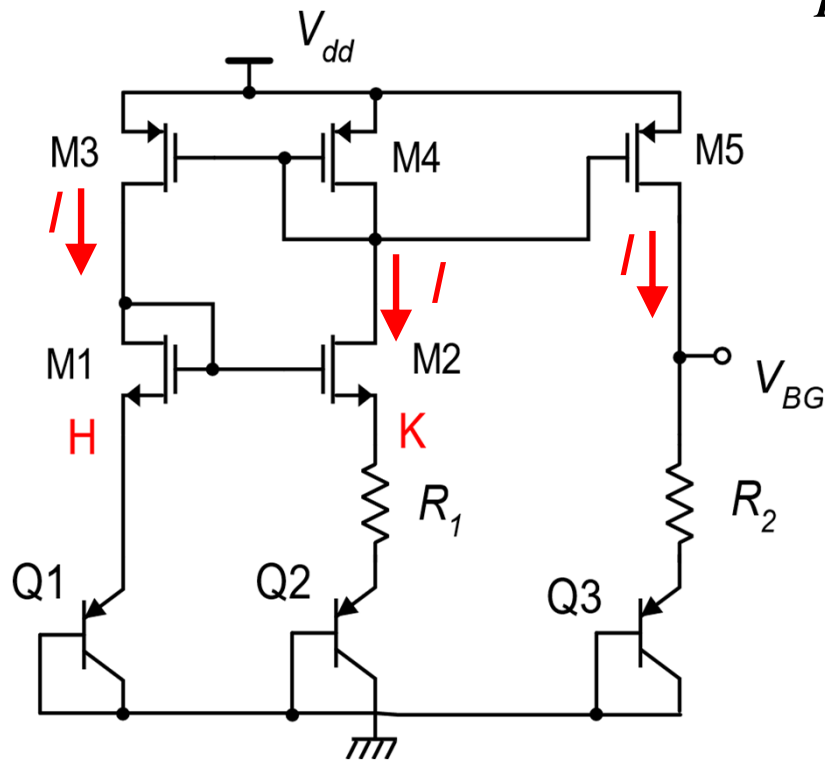
Common centroid layout  
For  $n=8$



Substrate PNPs

$$\frac{area_2}{area_1} = n > 1$$

# Band-Gap voltage: a CMOS compatible Circuit



$$I = \frac{1}{R_1} \frac{kT}{q} \ln(n)$$

$$V_{BG} = |V_{BE3}| + IR_2$$

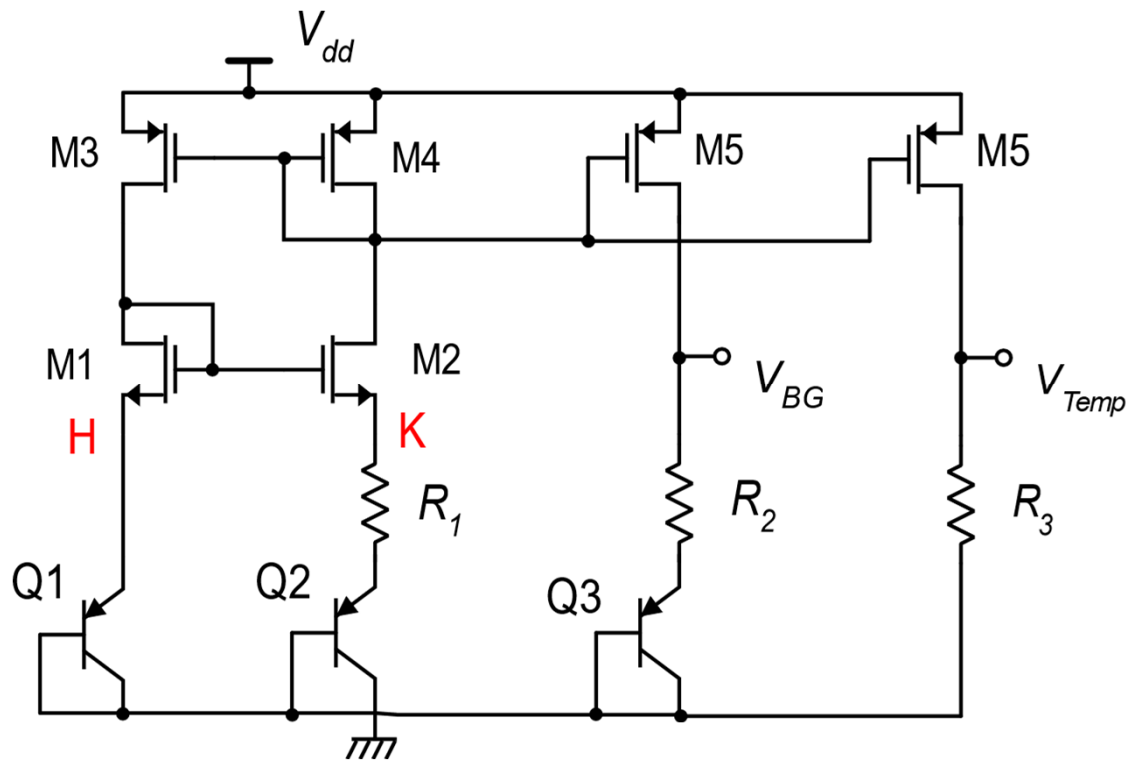
Biased with  $I$   
 $\alpha=1$

$$V_{BG} = |V_{BE3}| + \frac{R_2}{R_1} \frac{kT}{q} \ln(n)$$

$$V_{BG} = |V_{BE3}| + V_T \frac{R_2}{R_1} \ln(n)$$

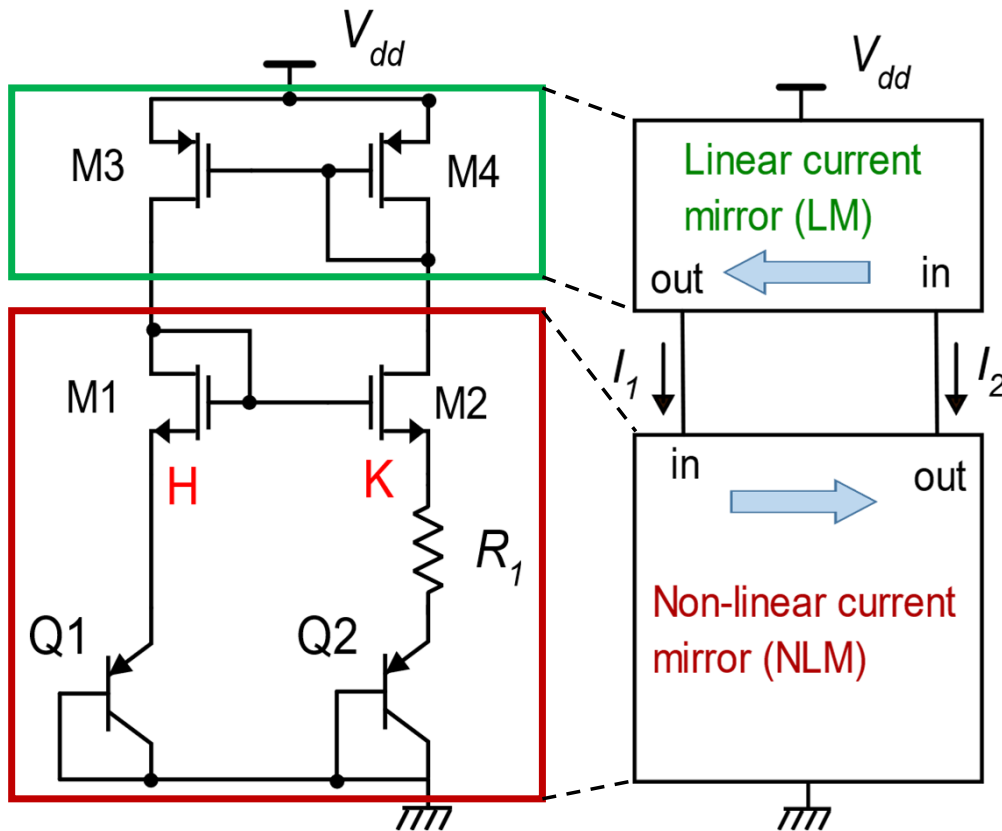
$$V_{BG} = V_{BE} + bV_T$$

# Deriving a temperature sensor from the Band-Gap circuit

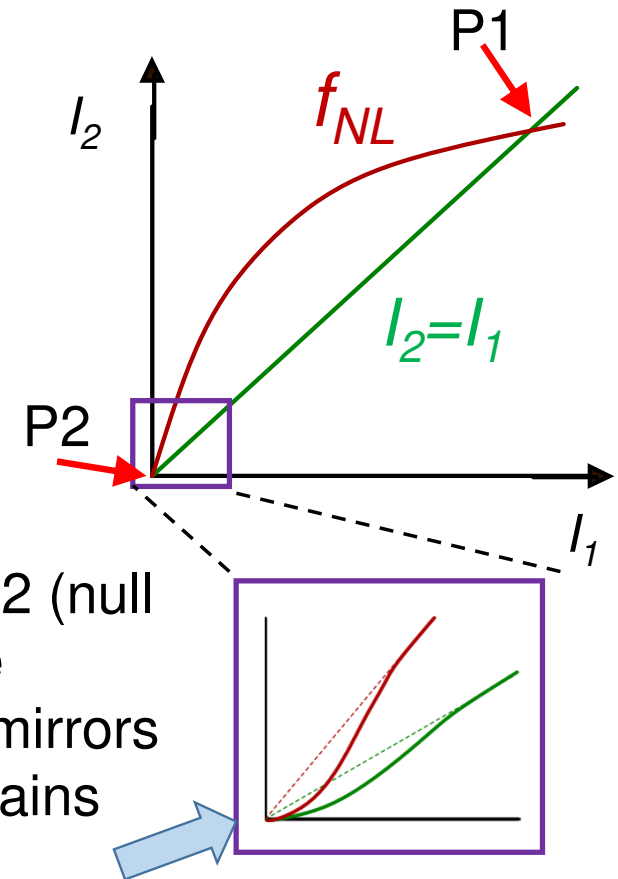
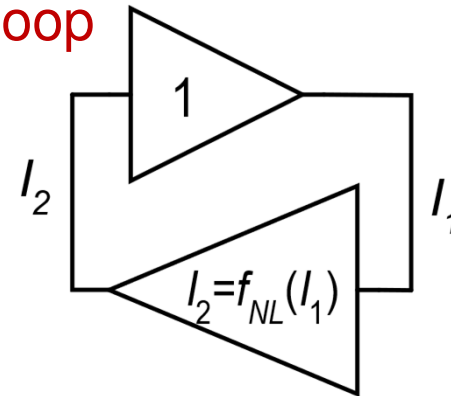


$$V_{Temp} = \frac{R_3}{R_1} \frac{kT}{q} \ln(n)$$

# PTAT current generator: multiple stable states



Positive feedback loop



P1 is the correct operating point. P2 (null currents) is stable because the two mirrors have very small gains around the origin.

**A start-up circuit is necessary to prevent the circuit from being trapped into P2**